



MPS8098



NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 10. See PN100 for characteristics.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	60	V
V _{CBO}	Collector-Base Voltage	60	V
V _{EBO}	Emitter-Base Voltage	6.0	V
Ic	Collector Current - Continuous	500	mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range -55 to +150 °C		°C

^{*}These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

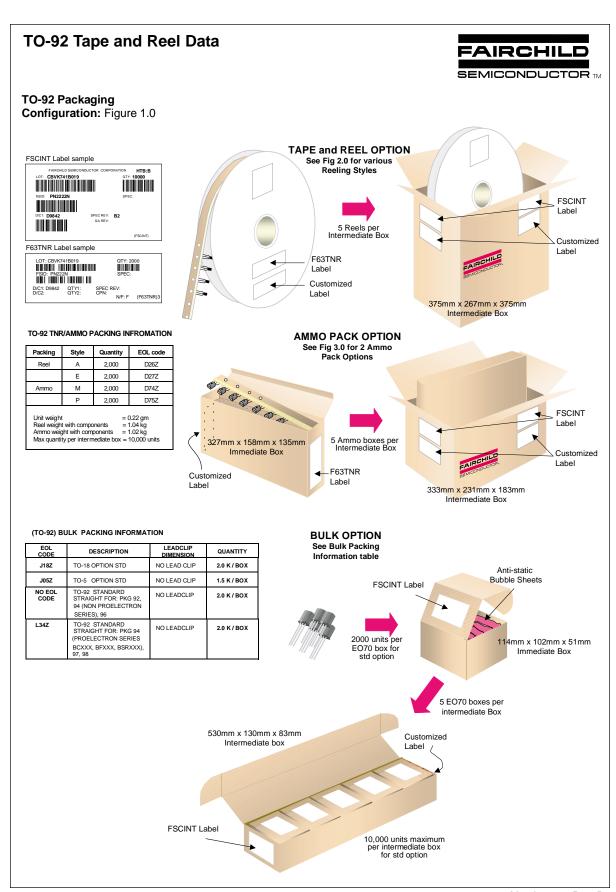
Symbol	Characteristic	Max	Units
		MPS8098	
P _D	Total Device Dissipation Derate above 25°C	625 5.0	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

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NPN General Purpose Amplifier (continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHA	RACTERISTICS				
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = 10 \text{ mA}, I_B = 0$	60		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	60		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10 \mu A, I_C = 0$	6.0		V
I _{CBO}	Collector Cutoff Current	$V_{CB} = 60 \text{ V}, I_{E} = 0$		0.1	μΑ
I _{CEO}	Collector Cutoff Current	$V_{CE} = 60 \text{ V}, I_{B} = 0$		0.1	μΑ
I _{EBO}	Emitter Cutoff Current	$V_{EB} = 6.0 \text{ V}, I_{C} = 0$		0.1	μΑ
	RACTERISTICS*				r-
					1
ON CHAF		$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$	100	300	
ON CHAF	RACTERISTICS*	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$	100 100 75	300	
ON CHAF	RACTERISTICS*	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$	100	300 0.4 0.3	V
	RACTERISTICS* DC Current Gain	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 100 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 5.0 \text{ mA}$	100	0.4	V
ON CHAF h _{FE} V _{CE(sat)} V _{BE(on)}	RACTERISTICS* DC Current Gain Collector-Emitter Saturation Voltage	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 100 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 5.0 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA}$	100 75	0.4 0.3	V
ON CHAF NFE VCE(sat) VBE(ON) SMALL S	RACTERISTICS* DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter On Voltage	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 100 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 5.0 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA}$	100 75	0.4 0.3	V
ON CHAF h _{FE} V _{CE(sat)} V _{BE(on)}	RACTERISTICS* DC Current Gain Collector-Emitter Saturation Voltage Base-Emitter On Voltage IGNAL CHARACTERISTICS	$V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 100 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 5.0 \text{ mA}$ $I_{C} = 100 \text{ mA}, I_{B} = 10 \text{ mA}$ $V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$	100 75	0.4 0.3 0.7	V

^{*}Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

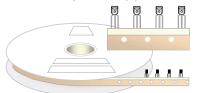


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TO-92 Tape and Reel Data, continued

TO-92 Reeling Style Configuration: Figure 2.0

Machine Option "A" (H)

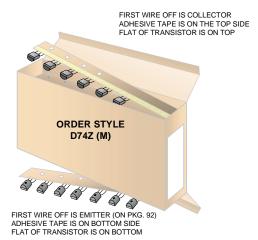


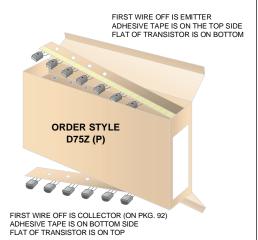
Style "A", D26Z, D70Z (s/h)

Machine Option "E" (J)

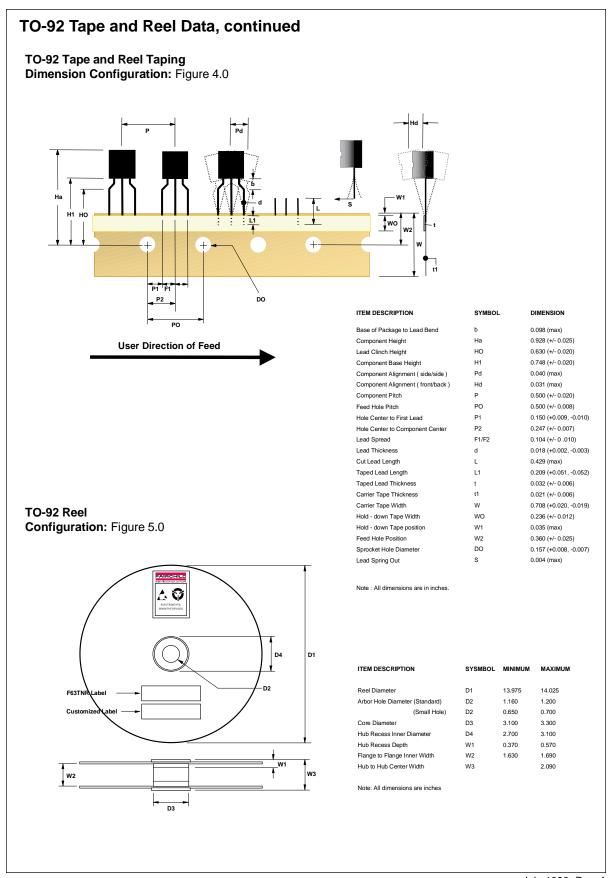
Style "E", D27Z, D71Z (s/h)

TO-92 Radial Ammo Packaging Configuration: Figure 3.0





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TO-92 Package Dimensions FAIRCHILD SEMICONDUCTOR TM TO-92 (FS PKG Code 92, 94, 96) Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters] Part Weight per unit (gram): 0.1977 0.185 4.70 0.170 4.32 TO-92 (92,94,96) 94 96 B F В В В D D 2 В S С G Ε Ø0.060 [Ø1.52] G В S С G 0.010 [0.254] DEEP 5.0°TYP.

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0.095 0.084 2.13

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